

UNR911xG Series

Silicon PNP epitaxial planar type

For digital circuits

■ Features

- Costs can be reduced through downsizing of the equipment and reduction of the number of parts.
- SS-Mini type package, allowing automatic insertion through tape packing.

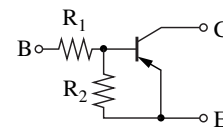
■ Resistance by Part Number

	Marking Symbol	(R ₁)	(R ₂)
• UNR9110G	6L	47 kΩ	—
• UNR9111G	6A	10 kΩ	10 kΩ
• UNR9112G	6B	22 kΩ	22 kΩ
• UNR9113G	6C	47 kΩ	47 kΩ
• UNR9114G	6D	10 kΩ	47 kΩ
• UNR9115G	6E	10 kΩ	—
• UNR9116G	6F	4.7 kΩ	—
• UNR9117G	6H	22 kΩ	—
• UNR9118G	6I	0.51 kΩ	5.1 kΩ
• UNR9119G	6K	1 kΩ	10 kΩ
• UNR911AG	6X	100 kΩ	100 kΩ
• UNR911BG	6Y	100 kΩ	—
• UNR911CG	6Z	—	47 kΩ
• UNR911DG	6M	47 kΩ	10 kΩ
• UNR911EG	6N	47 kΩ	22 kΩ
• UNR911FG	6O	4.7 kΩ	10 kΩ
• UNR911HG	6P	2.2 kΩ	10 kΩ
• UNR911LG	6Q	4.7 kΩ	4.7 kΩ
• UNR911MG	EI	2.2 kΩ	47 kΩ
• UNR911NG	EW	4.7 kΩ	47 kΩ
• UNR911TG	EY	22 kΩ	47 kΩ
• UNR911VG	FC	2.2 kΩ	2.2 kΩ

■ Package

- Code
SSMini3-F3
- Pin Name
1: Base
2: Emitter
3: Collector

■ Internal Connection



■ Absolute Maximum Ratings T_a = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	-50	V
Collector-emitter voltage (Base open)	V _{CEO}	-50	V
Collector current	I _C	-100	mA
Total power dissipation	P _T	125	mW
Junction temperature	T _j	125	°C
Storage temperature	T _{stg}	-55 to +125	°C

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

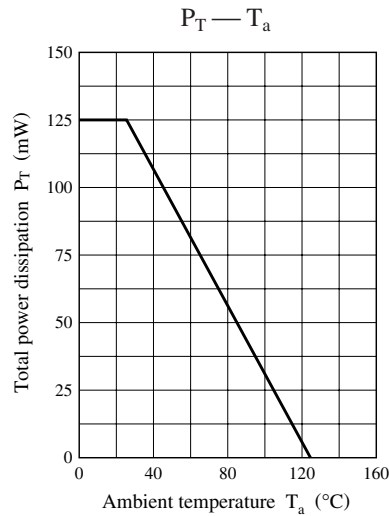
Parameter		Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)		V_{CBO}	$I_C = -10 \mu\text{A}, I_E = 0$	-50			V
Collector-emitter voltage (Base open)		V_{CEO}	$I_C = -2 \text{ mA}, I_B = 0$	-50			V
Collector-base cutoff current (Emitter open)		I_{CBO}	$V_{CB} = -50 \text{ V}, I_E = 0$			-0.1	μA
Collector-base cutoff current (Emitter open)		I_{CEO}	$V_{CE} = -50 \text{ V}, I_B = 0$			-0.5	μA
Emitter-base cutoff current (Collector open)	UNR9110G/9115G/ 9116G/9117G/911BG	I_{EBO}	$V_{EB} = -6 \text{ V}, I_C = 0$			-0.01	mA
	UNR9113G/911AG					-0.1	
	UNR9112G/9114G/911DG/ 911EG/911MG/911NG/911TG					-0.2	
	UNR9111G					-0.5	
	UNR911FG/911HG					-1.0	
	UNR9119G					-1.5	
	UNR9118G/911CG/911LG/911VG					-2.0	
Forward current transfer ratio	UNR911VG	h_{FE}	$V_{CE} = -10 \text{ V}, I_C = -5 \text{ mA}$	6		20	—
	UNR9118G/911LG			20			
	UNR9119G/911DG/911FG/911HG			30			
	UNR9111G			35			
	UNR9112G/911EG			60			
	UNR9113G/9114G/ 911AG/911CG/911MG			80			
	UNR911NG/911TG			80		400	
	UNR9110G/9115G/ 9116G/9117G/911BG			160		460	
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = -10 \text{ mA}, I_B = -0.3 \text{ mA}$			-0.25	V
	UNR911VG		$I_C = -10 \text{ mA}, I_B = -1.5 \text{ mA}$				
Output voltage high-level		V_{OH}	$V_{CC} = -5 \text{ V}, V_B = -0.5 \text{ V}, R_L = 1 \text{ k}\Omega$	-4.9			V
Output voltage low-level		V_{OL}	$V_{CC} = -5 \text{ V}, V_B = -2.5 \text{ V}, R_L = 1 \text{ k}\Omega$			-0.2	V
			UNR9113G/911BG	$V_{CC} = -5 \text{ V}, V_B = -3.5 \text{ V}, R_L = 1 \text{ k}\Omega$			
			UNR911DG	$V_{CC} = -5 \text{ V}, V_B = -10 \text{ V}, R_L = 1 \text{ k}\Omega$			
			UNR911EG	$V_{CC} = -5 \text{ V}, V_B = -6 \text{ V}, R_L = 1 \text{ k}\Omega$			
			UNR911AG	$V_{CC} = -5 \text{ V}, V_B = -5 \text{ V}, R_L = 1 \text{ k}\Omega$			
Transition frequency		f_T	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		80		MHz
UNR9113G			$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		150		
UNR911AG			$V_{CB} = -10 \text{ V}, I_E = 2 \text{ mA}, f = 200 \text{ MHz}$		80		
UNR911CG			$V_{CB} = -10 \text{ V}, I_E = 2 \text{ mA}, f = 200 \text{ MHz}$		150		
Input resistance	UNR9118G	R_1		-30%	0.51	+30%	$\text{k}\Omega$
	UNR9119G			1.0			
	UNR911HG/911MG/911VG			2.2			
	UNR9116G/911FG/911LG/911NG			4.7			
	UNR9111G/9114G/9115G			10			
	UNR9112G/9117G/911TG			22			
	UNR9110G/9113G/911DG/911EG			47			
	UNR911AG/911BG			100			

■ Electrical Characteristics (continued) $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

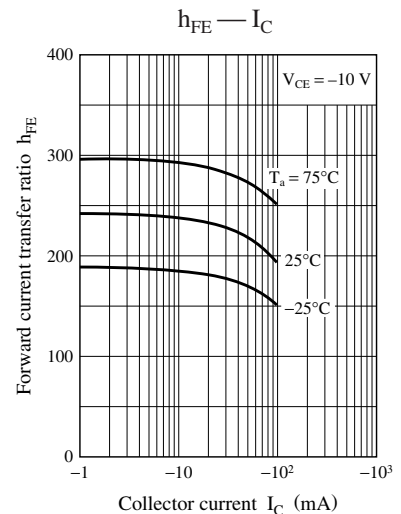
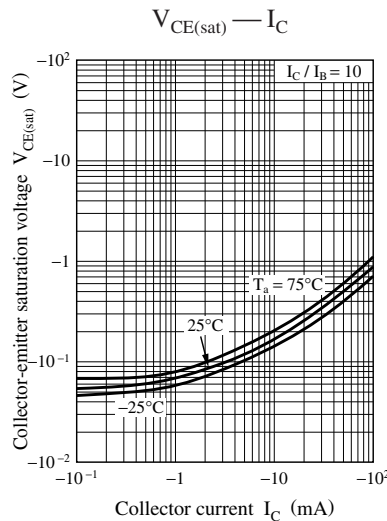
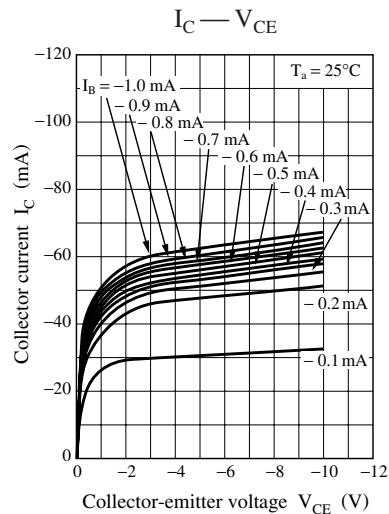
Parameter		Symbol	Conditions	Min	Typ	Max	Unit
Emitter-base resistance	UNR911CG	R_2		-30%	47	+30%	k Ω
Resistance ratio	UNR911MG	R_1/R_2			0.047		—
	UNR911NG				0.1		
	UNR9118G/9119G			0.08	0.10	0.12	
	UNR9114G			0.17	0.21	0.25	
	UNR911HG			0.17	0.22	0.27	
	UNR911TG				0.47		
	UNR911FG			0.37	0.47	0.57	
	UNR911AG/911VG				1.0		
	UNR911G/9112G/9113G/911LG			0.8	1.0	1.2	
	UNR911EG			1.70	2.14	2.60	
	UNR911DG			3.7	4.7	5.7	

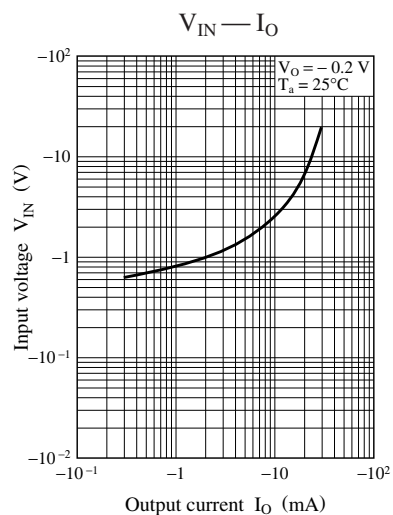
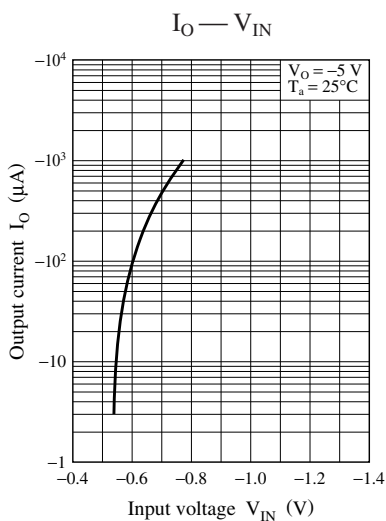
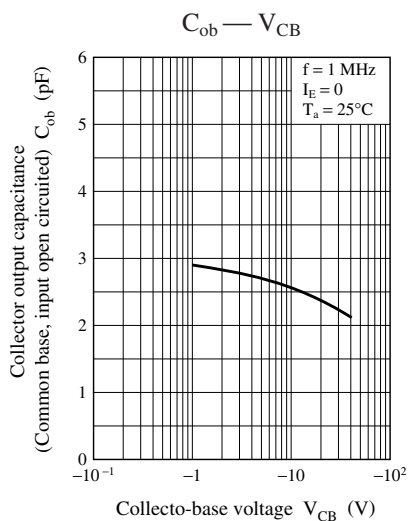
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

Common characteristics chart

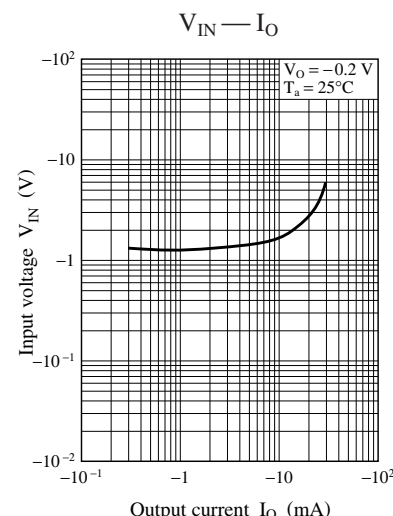
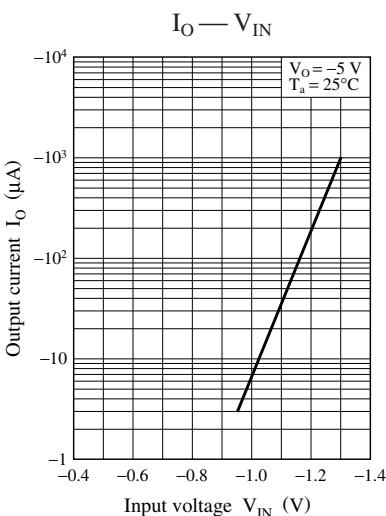
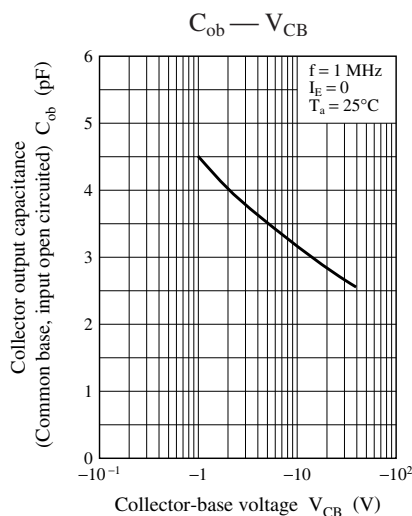
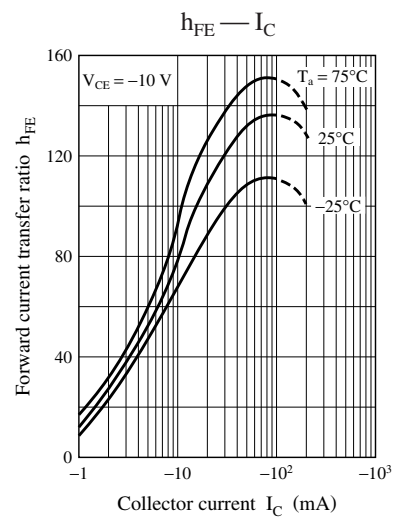
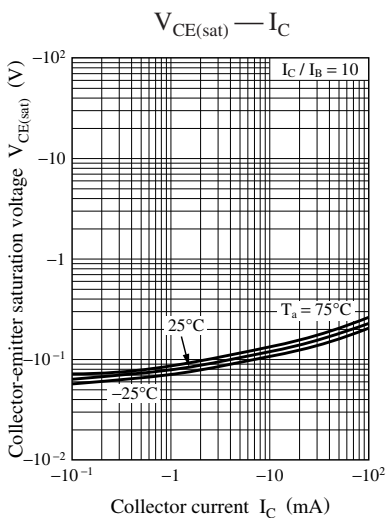
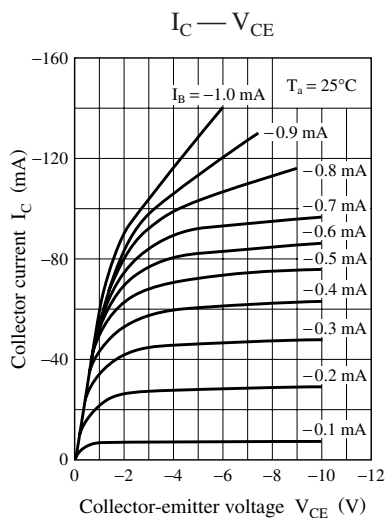


Characteristics charts of UNR9110G

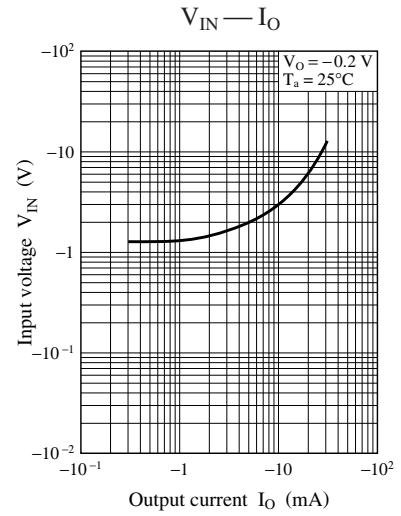
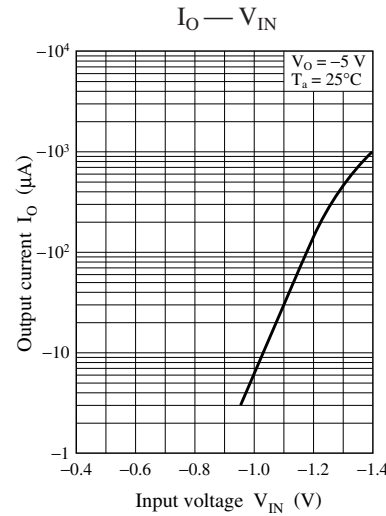
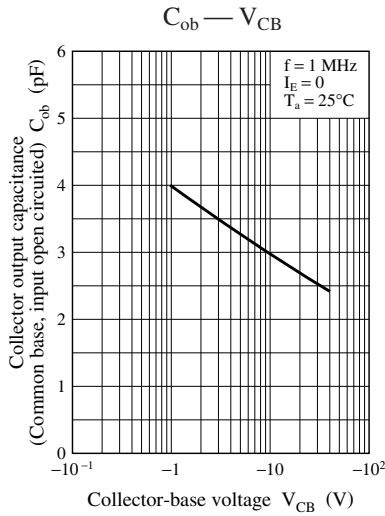
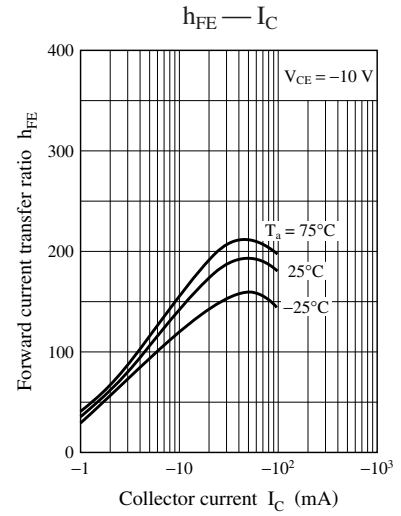
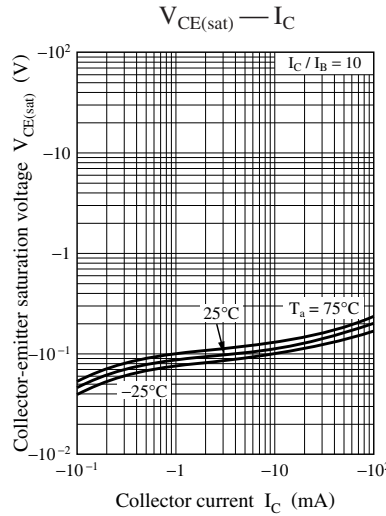
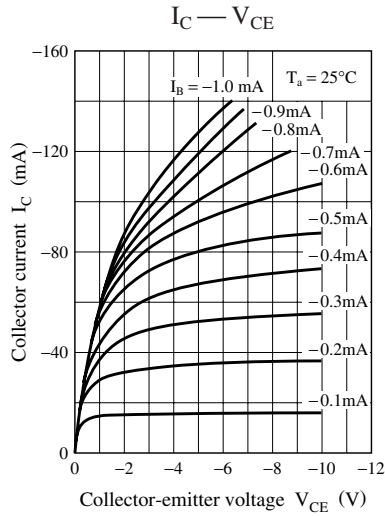




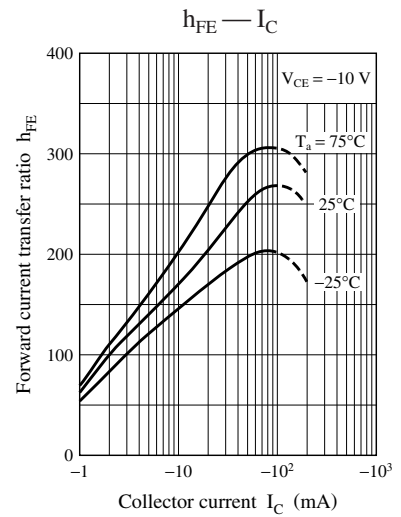
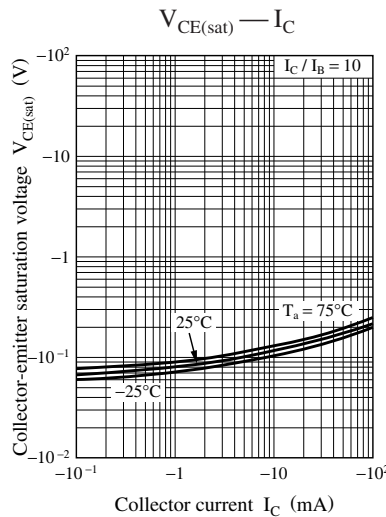
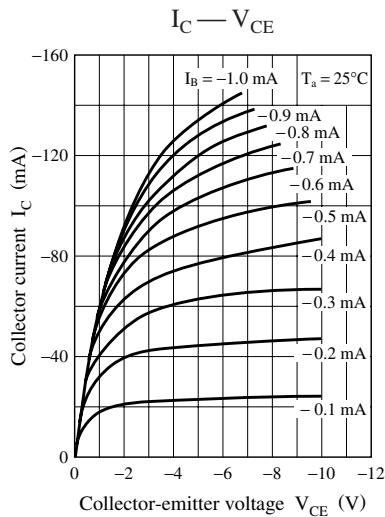
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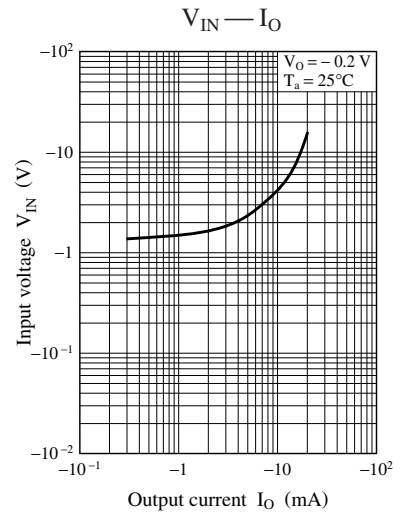
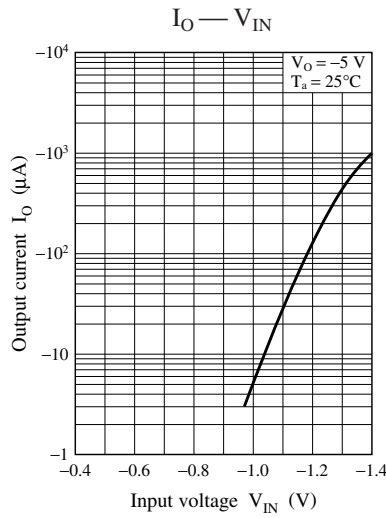
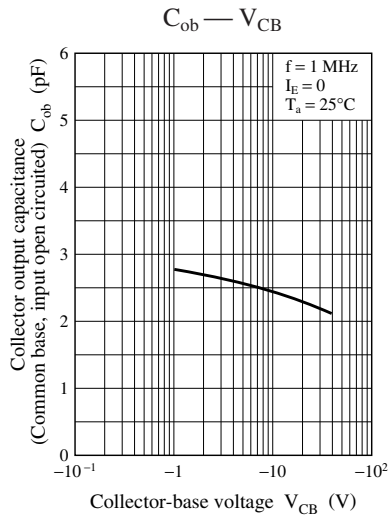


Characteristics charts of UNR9112G

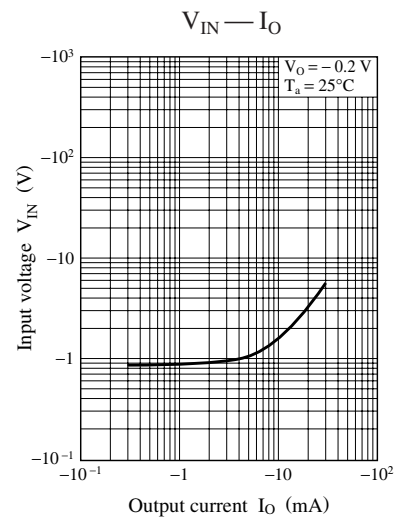
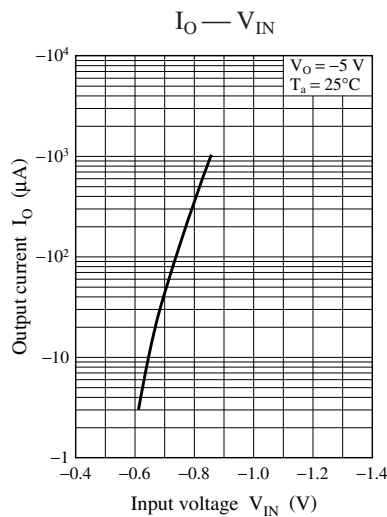
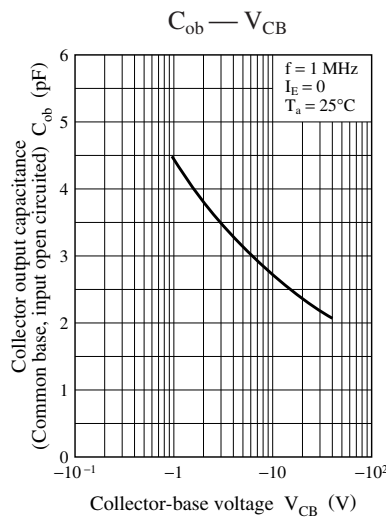
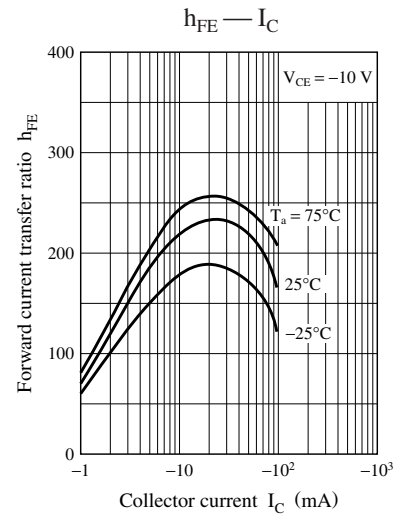
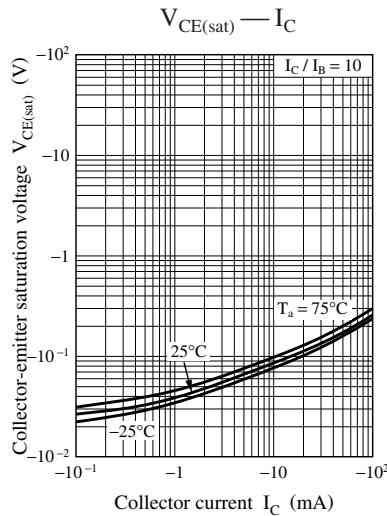
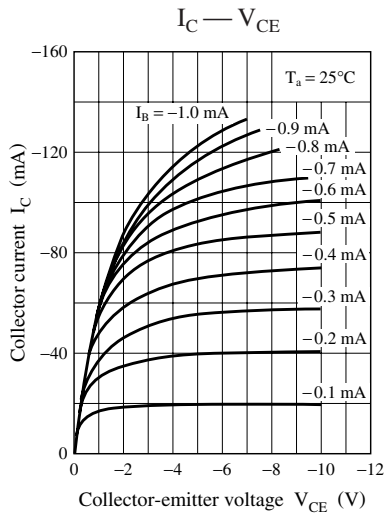


Characteristics charts of UNR9113G

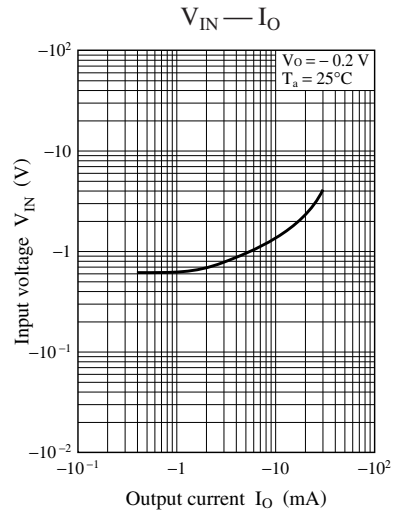
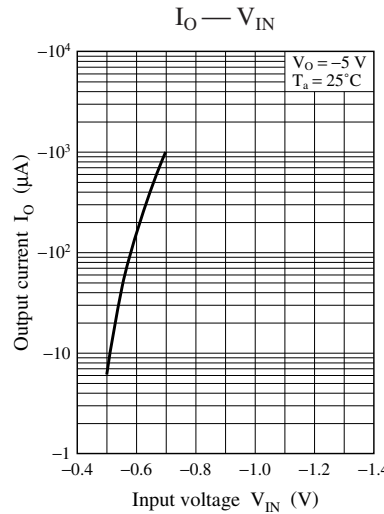
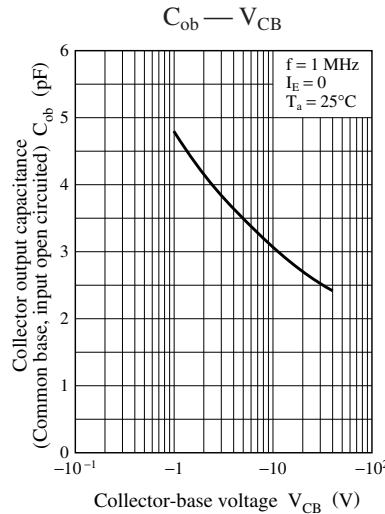
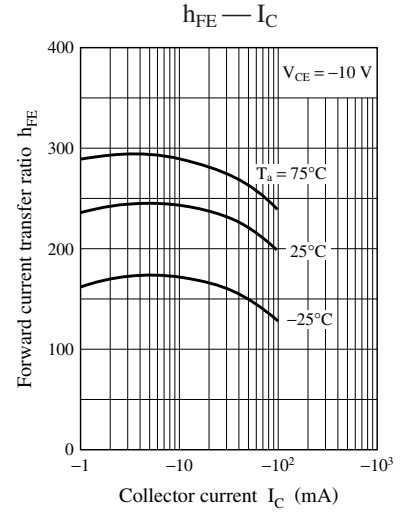
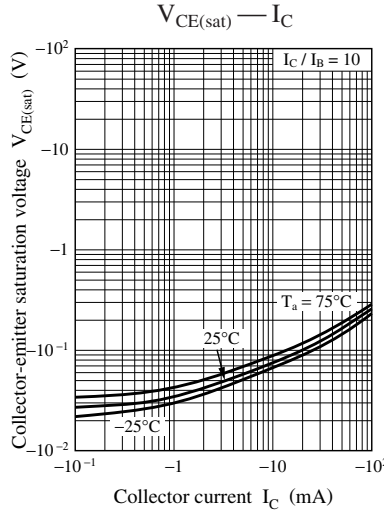
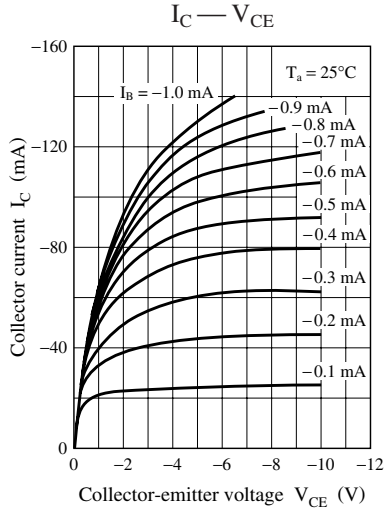




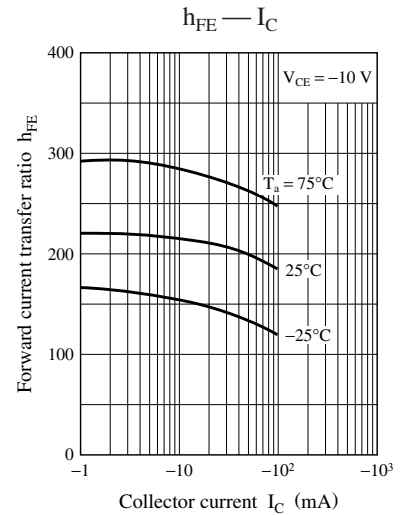
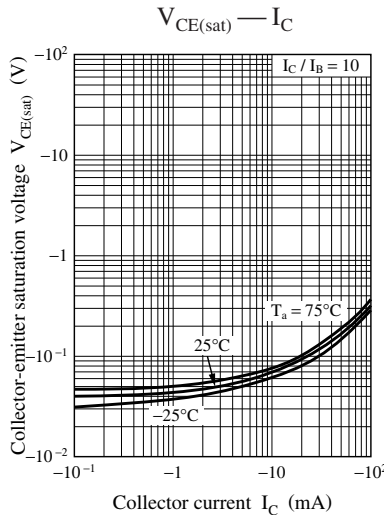
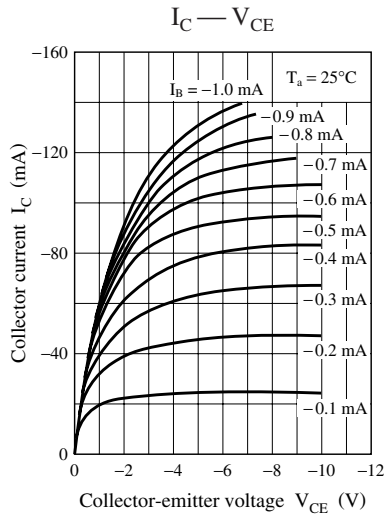
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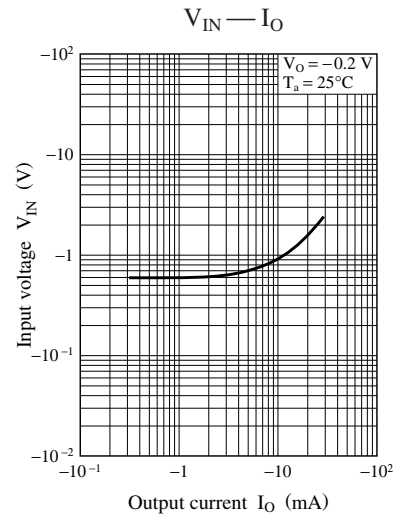
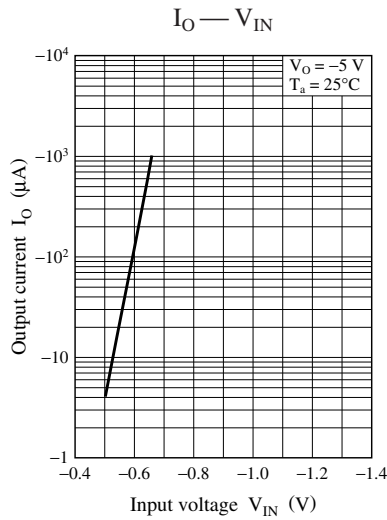
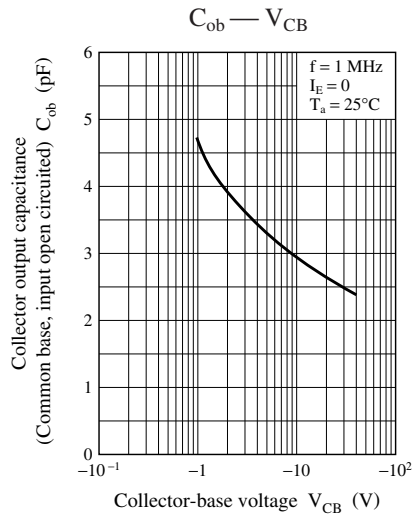


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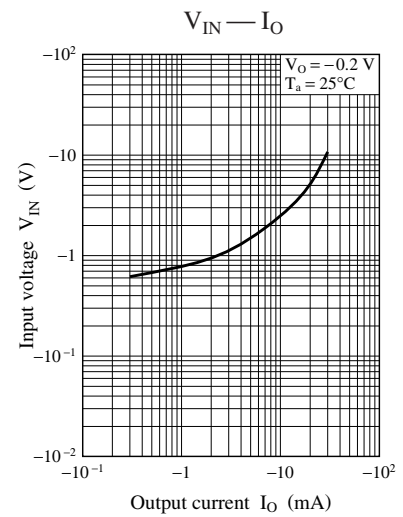
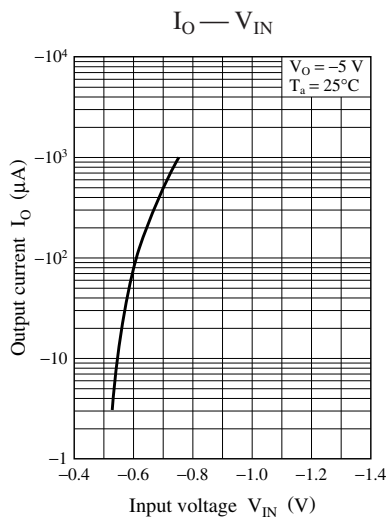
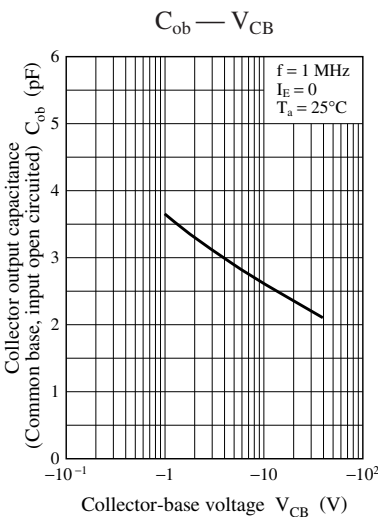
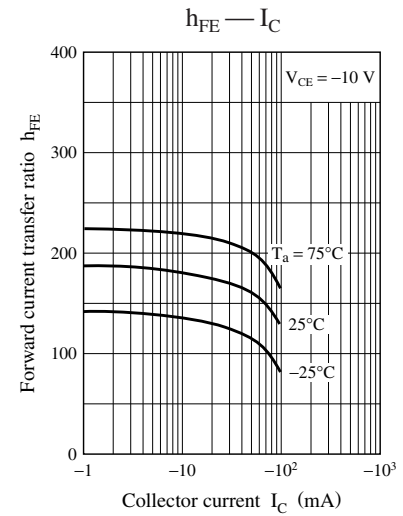
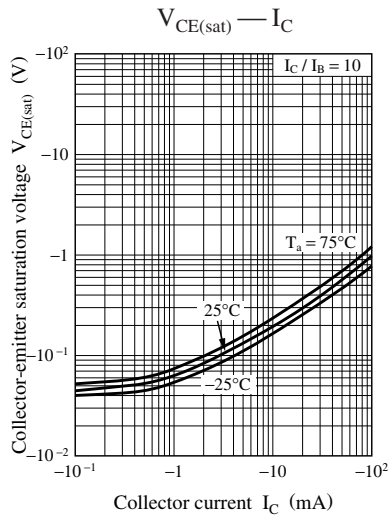
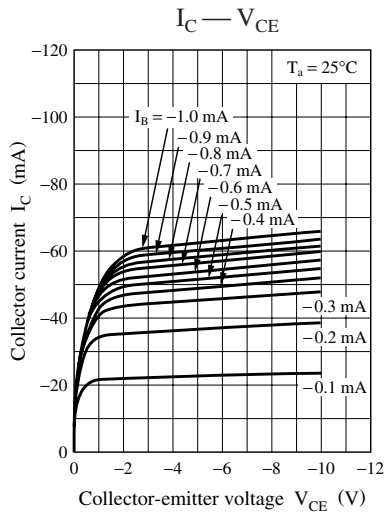


Characteristics charts of UNR9116G

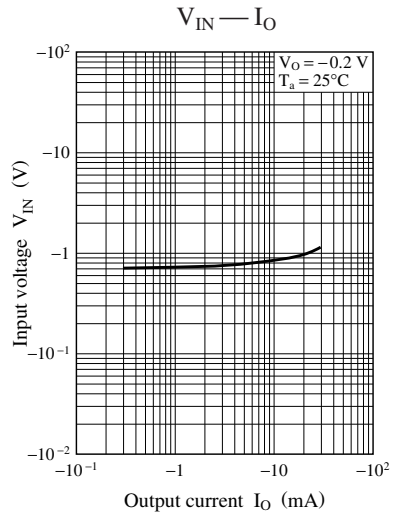
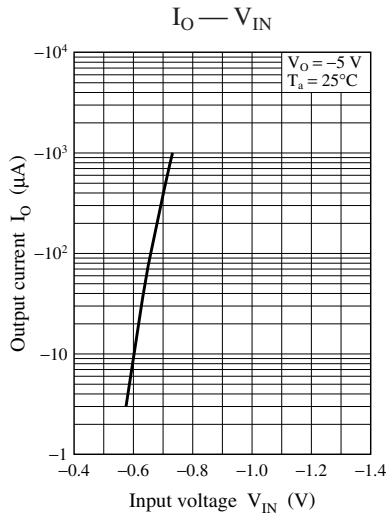
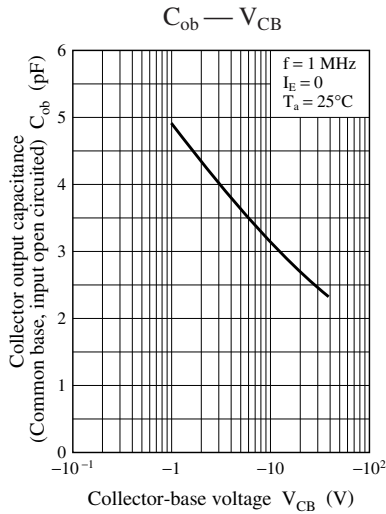
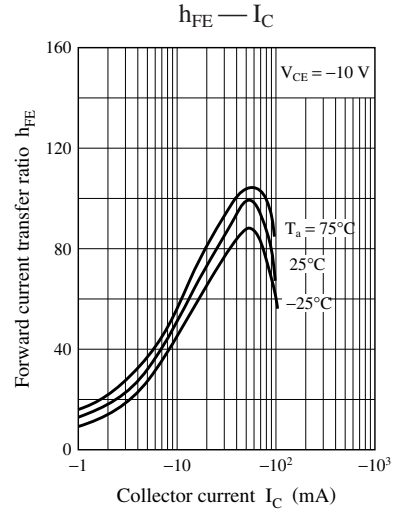
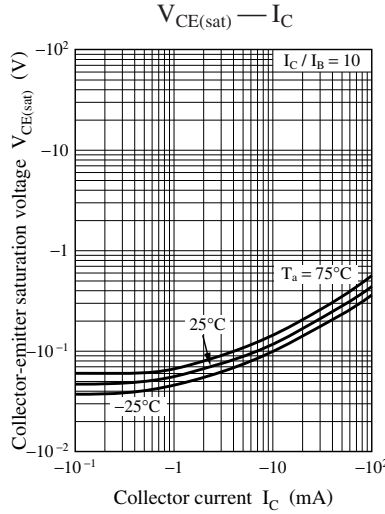
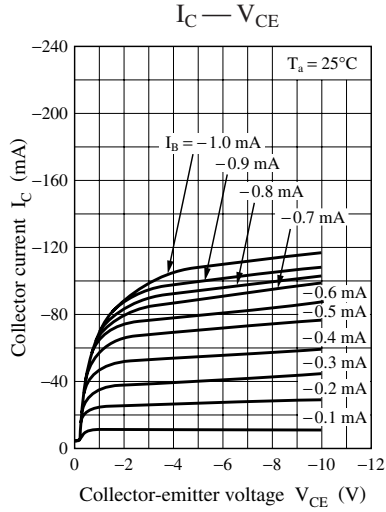




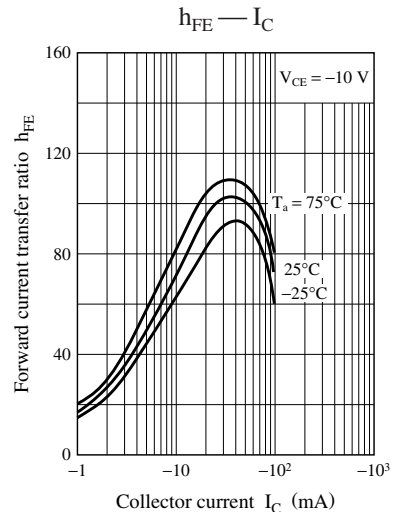
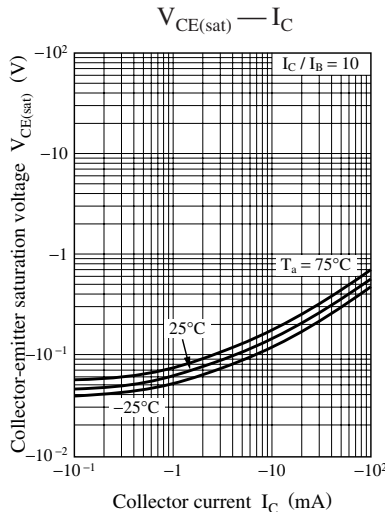
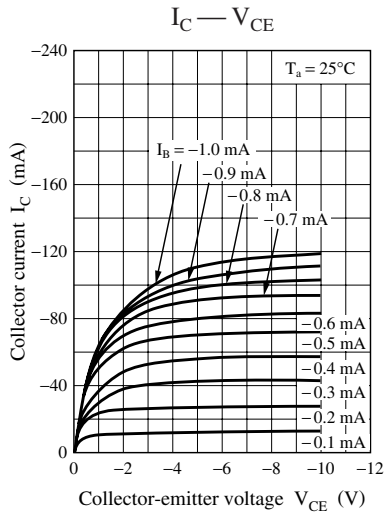
Characteristics charts of UNR9117G

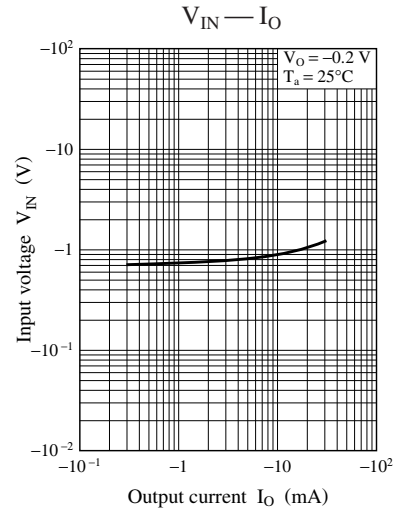
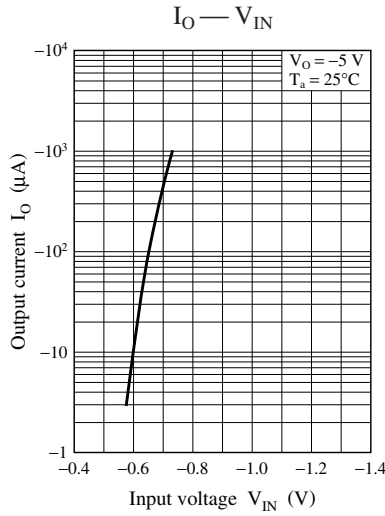
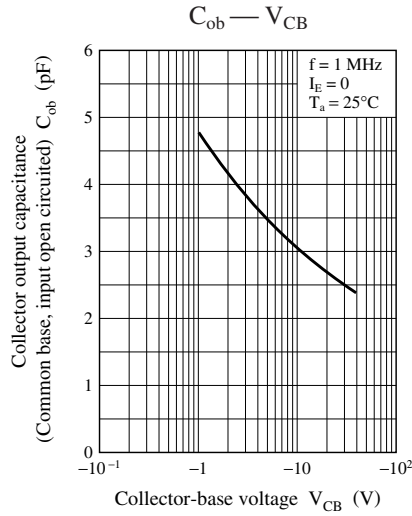


Characteristics charts of UNR9118G

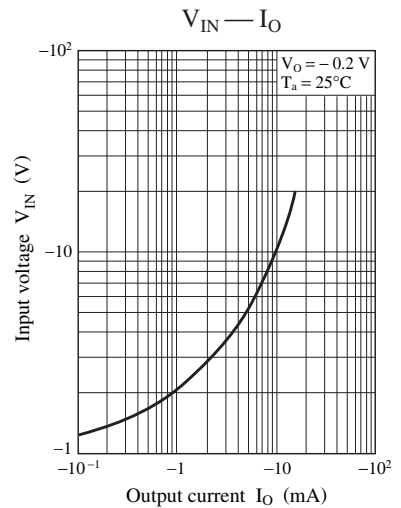
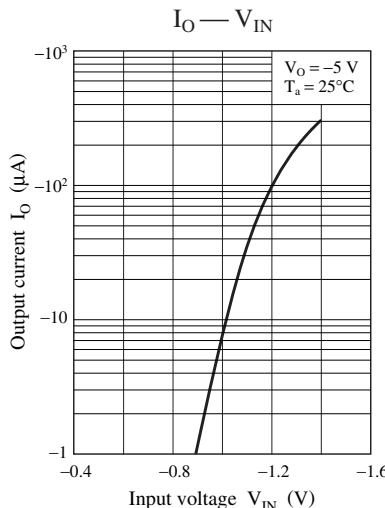
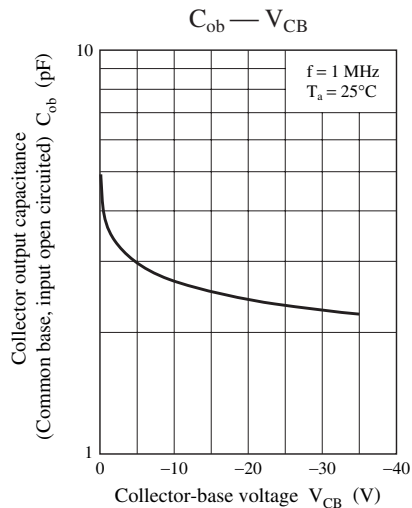
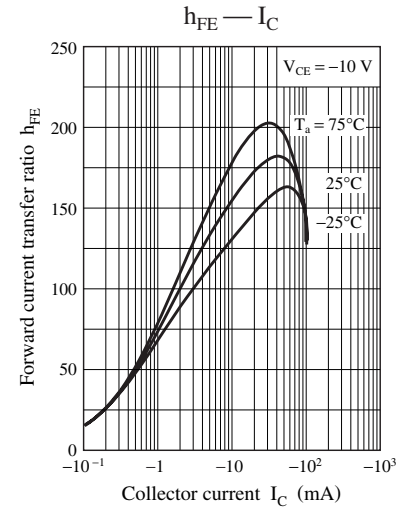
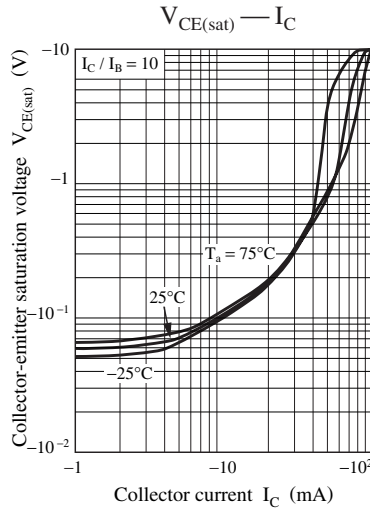
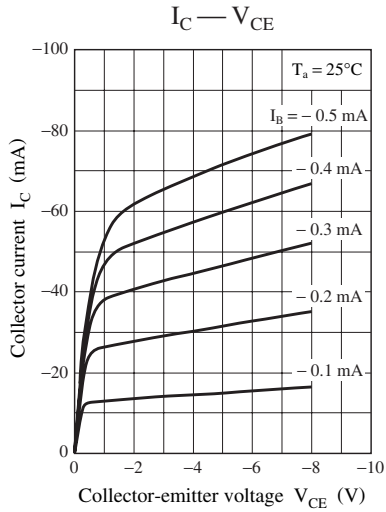


Characteristics charts of UNR9119G

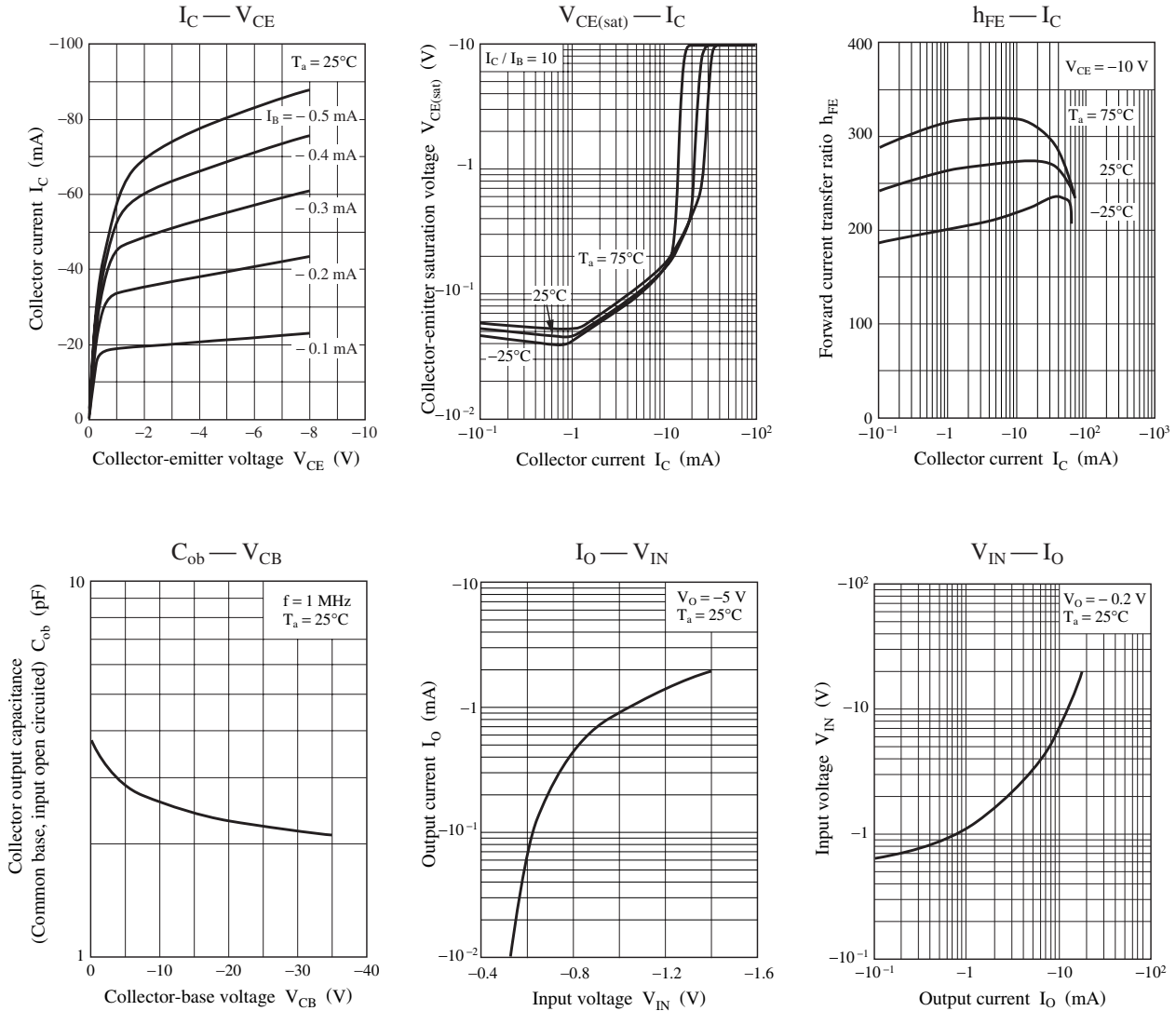




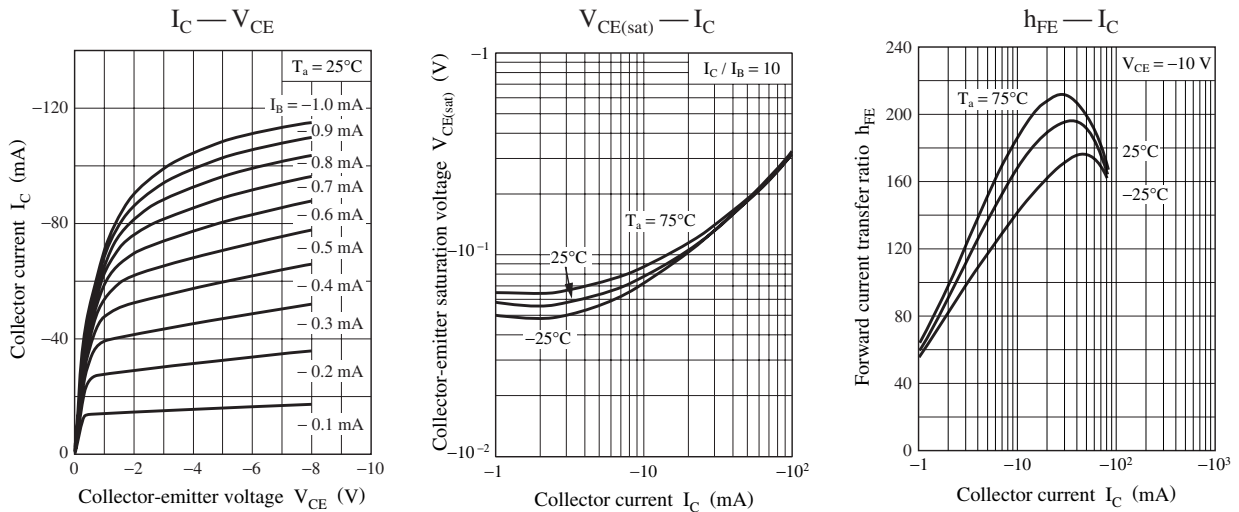
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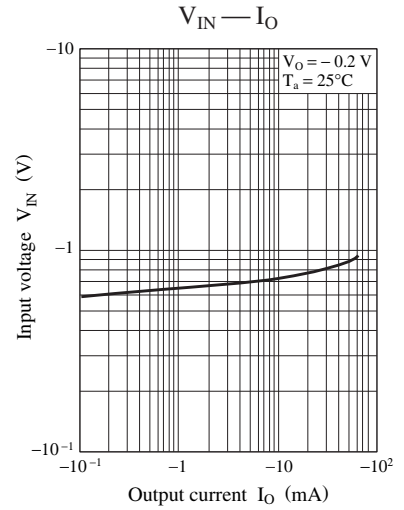
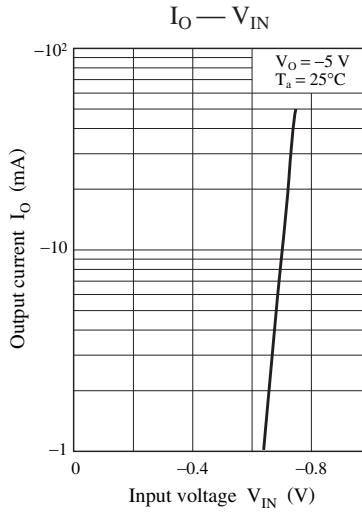
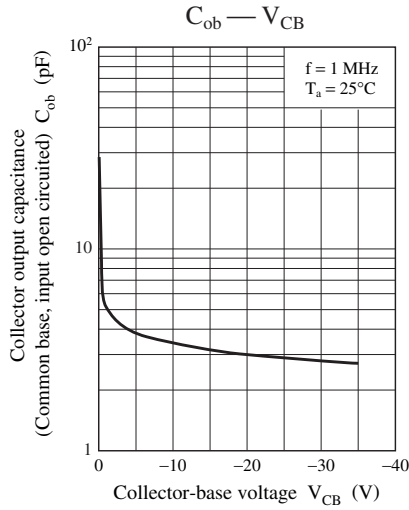


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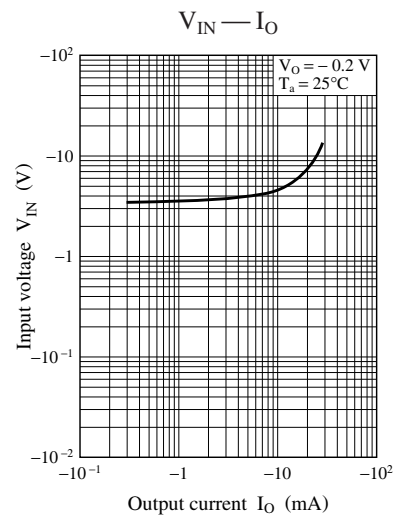
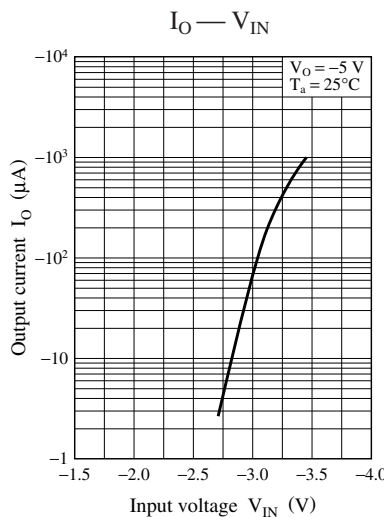
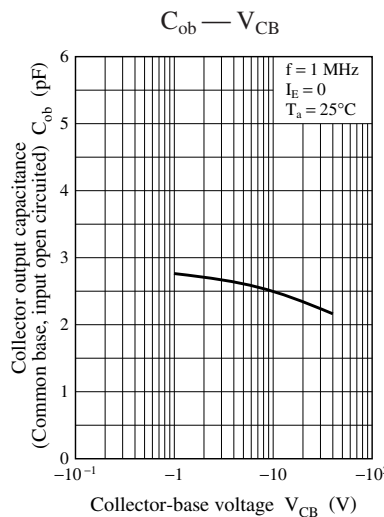
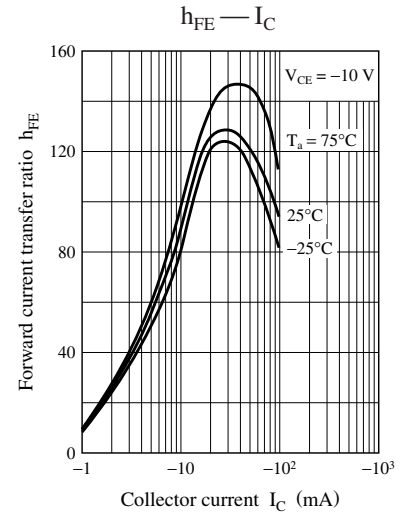
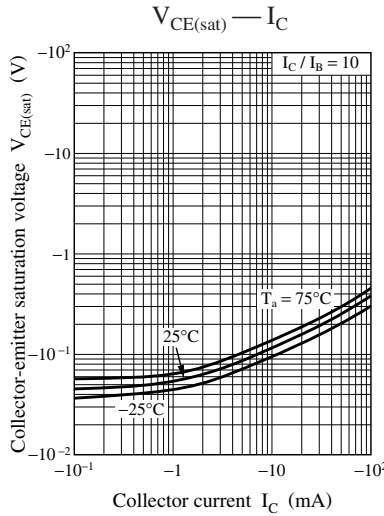
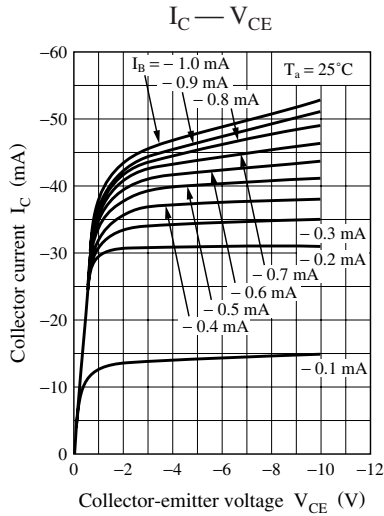


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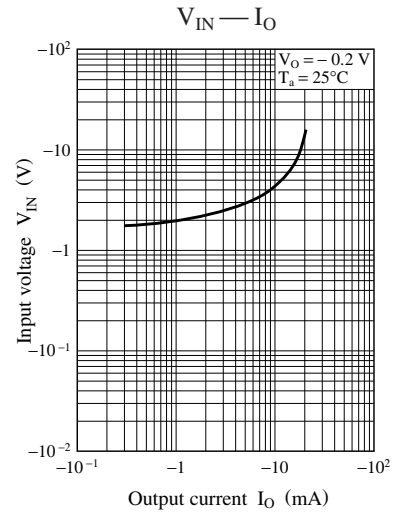
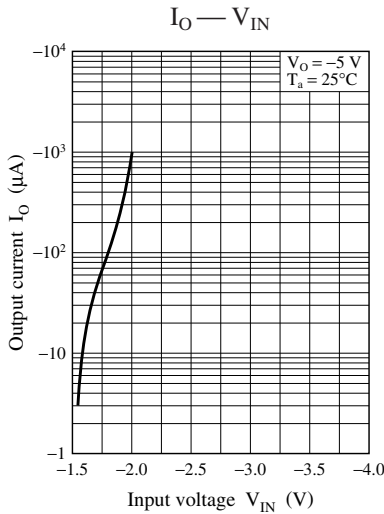
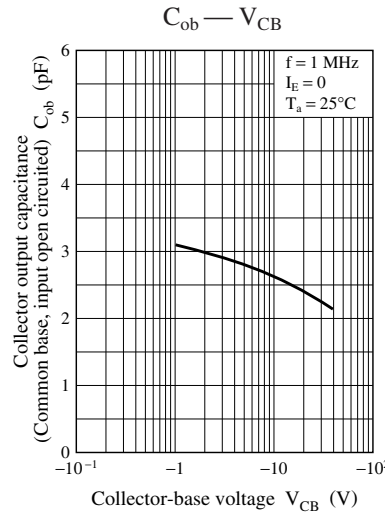
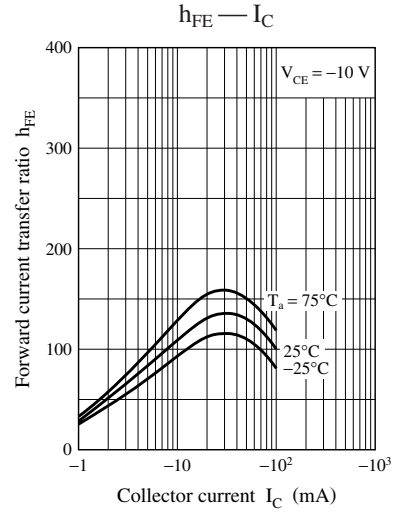
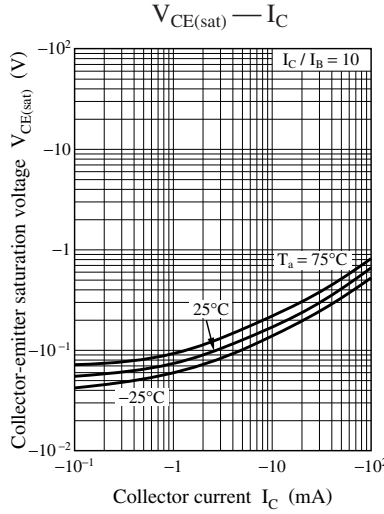
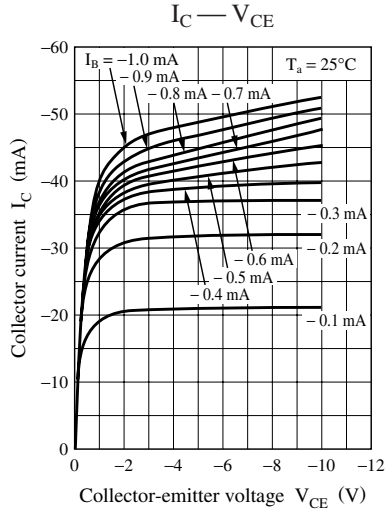




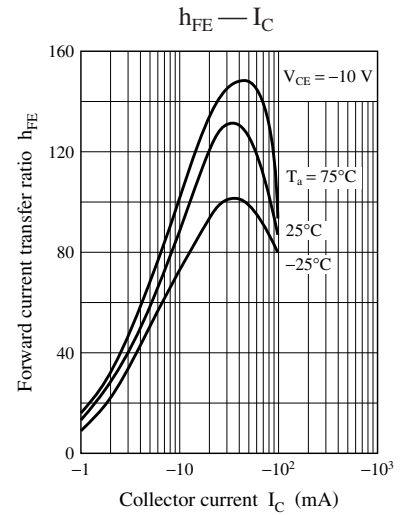
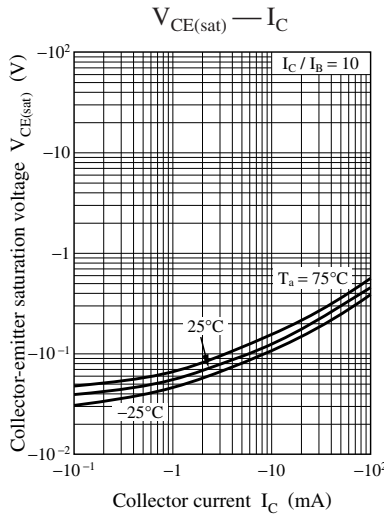
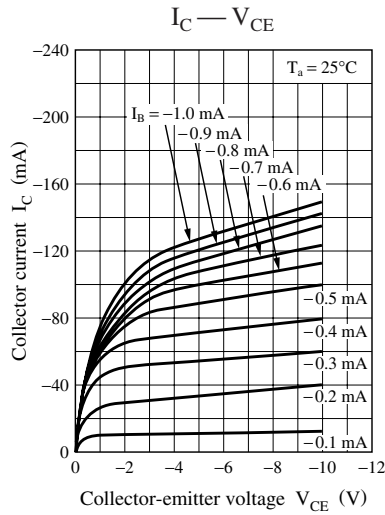
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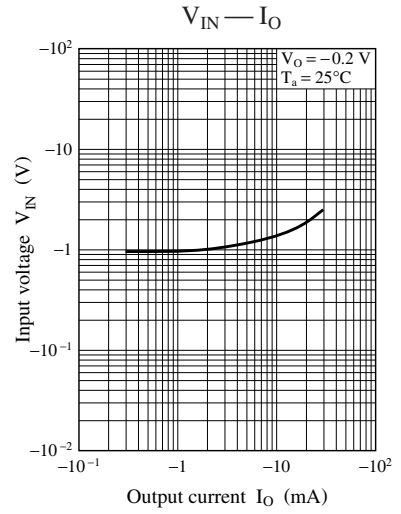
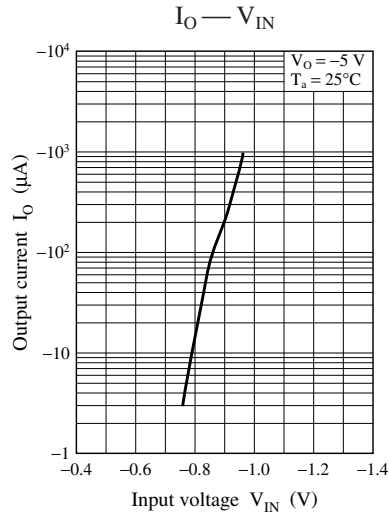
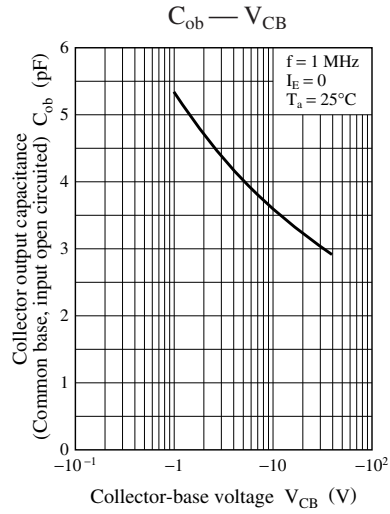


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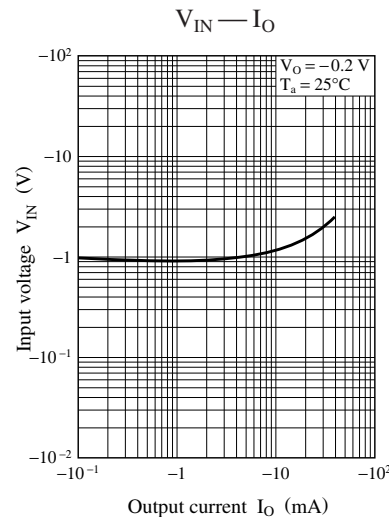
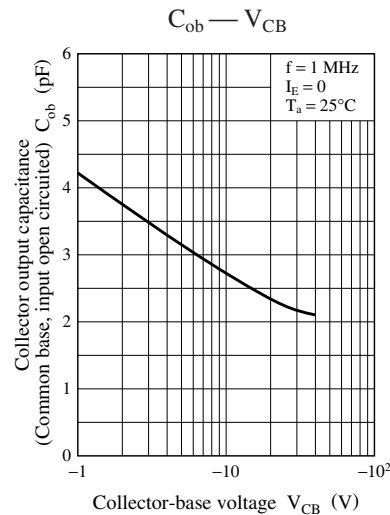
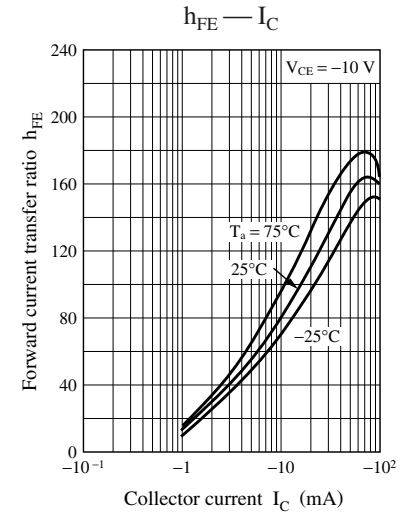
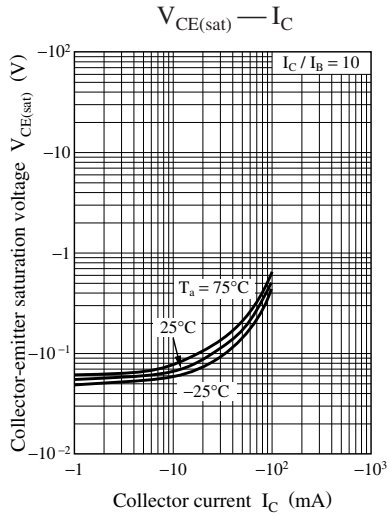
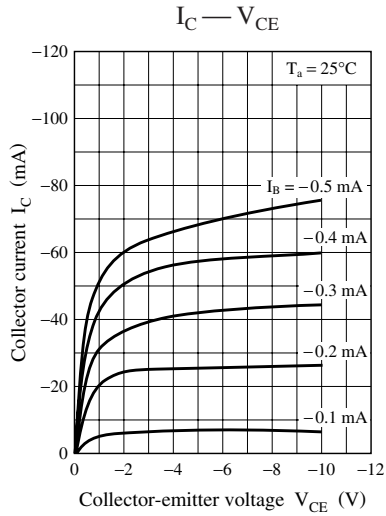


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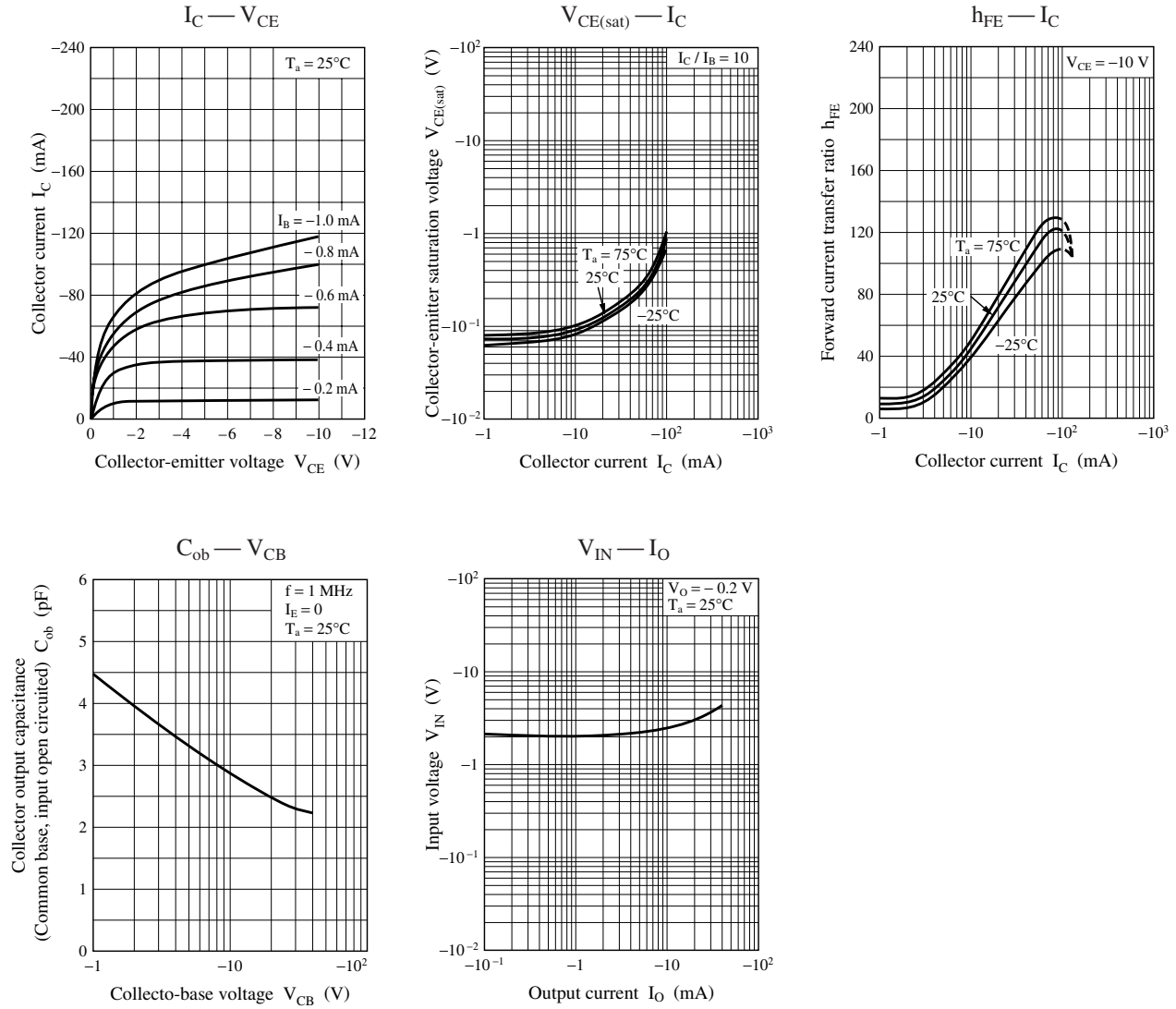




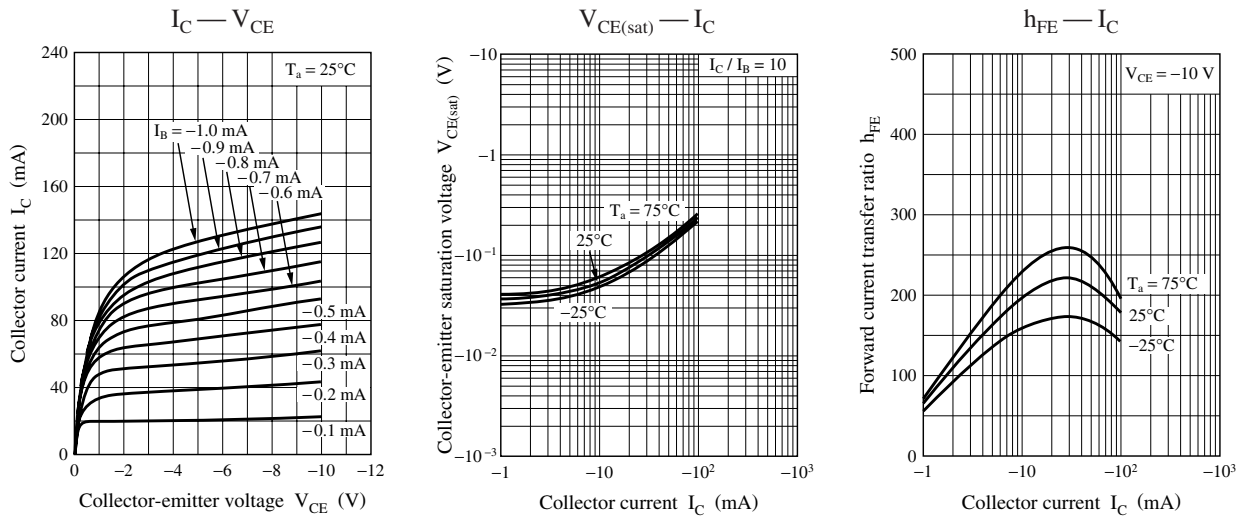
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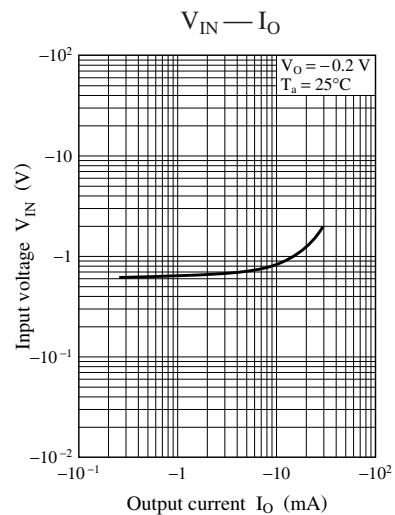
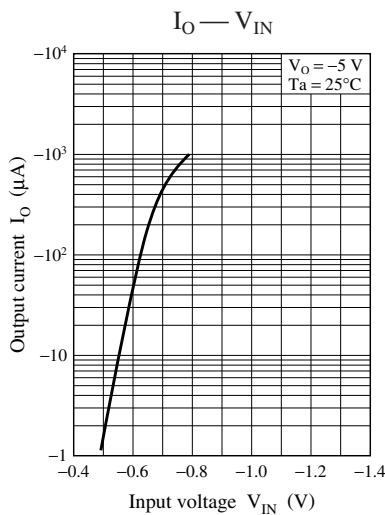
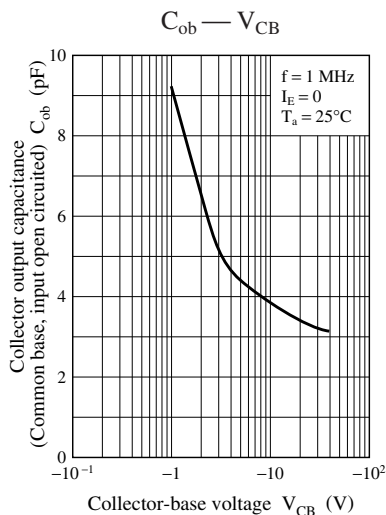


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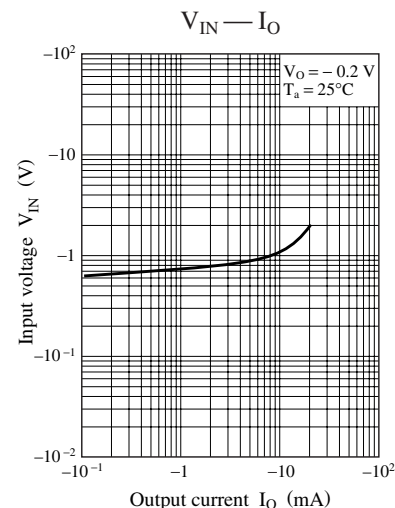
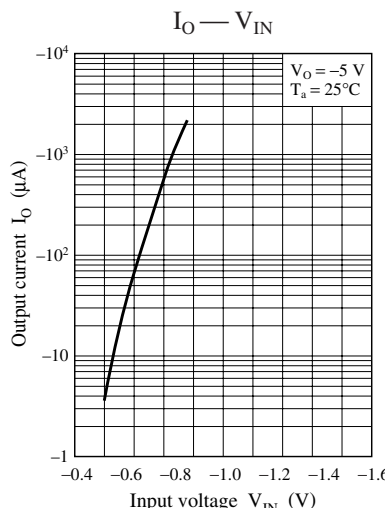
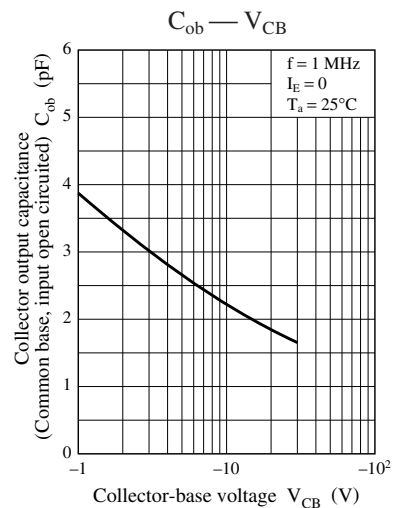
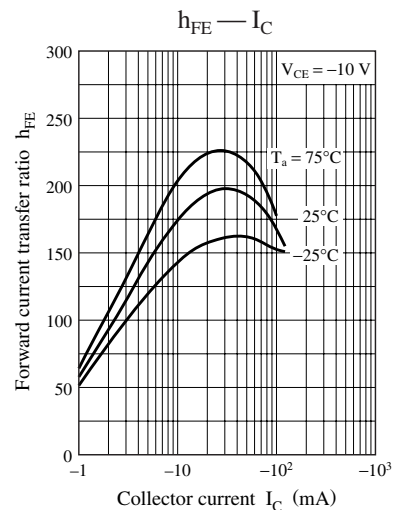
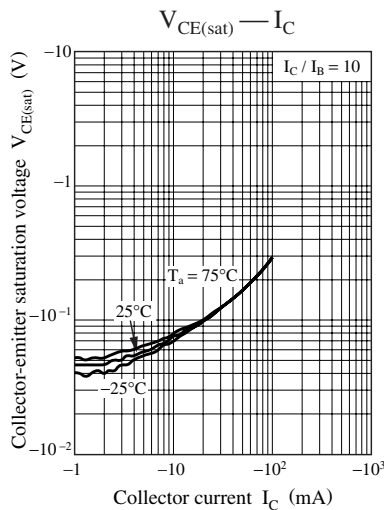
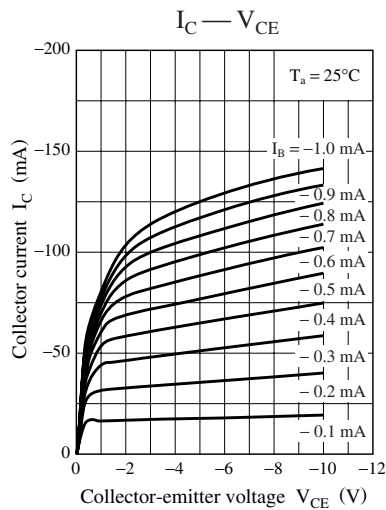


Characteristics charts of UNR911MG

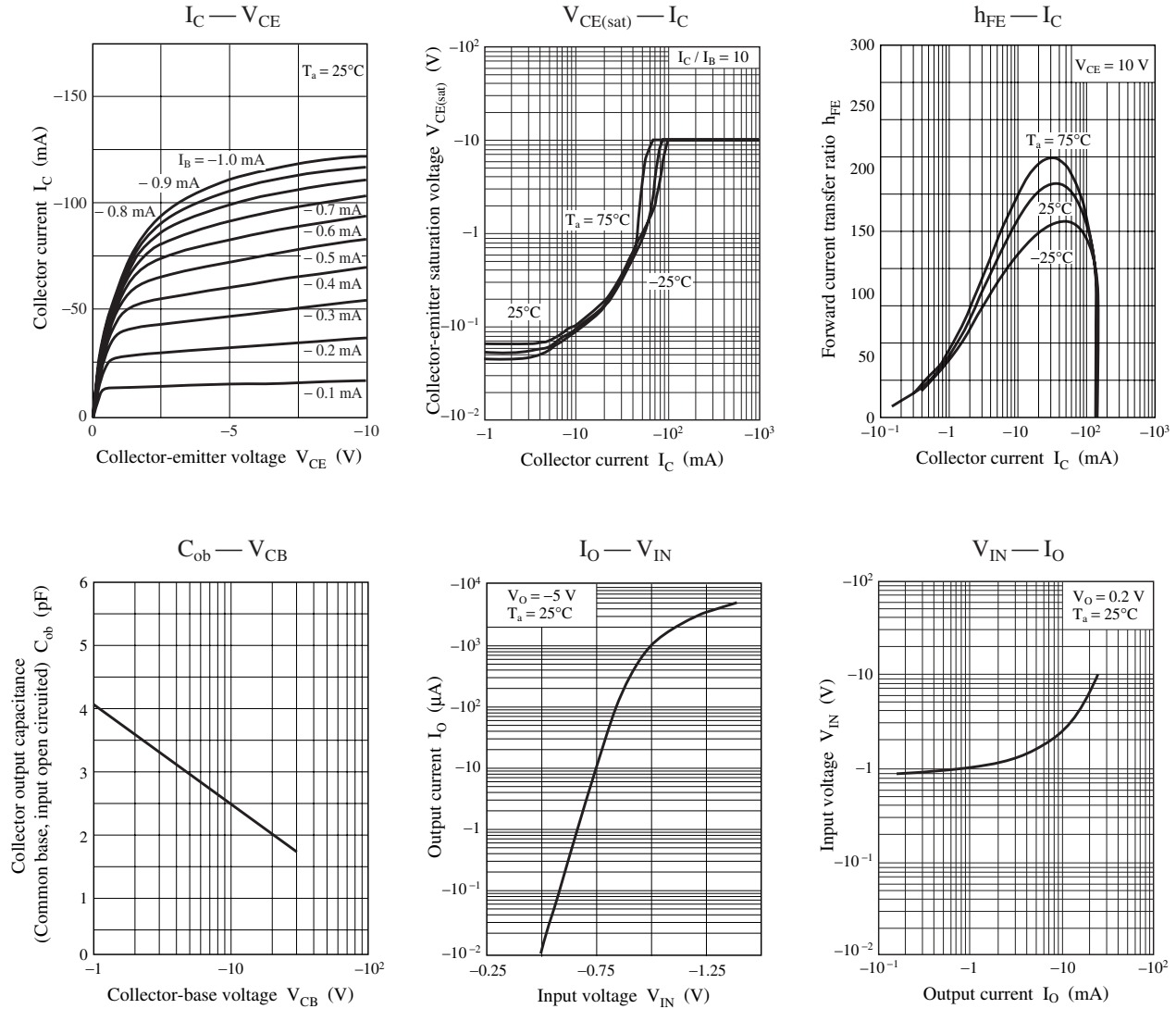




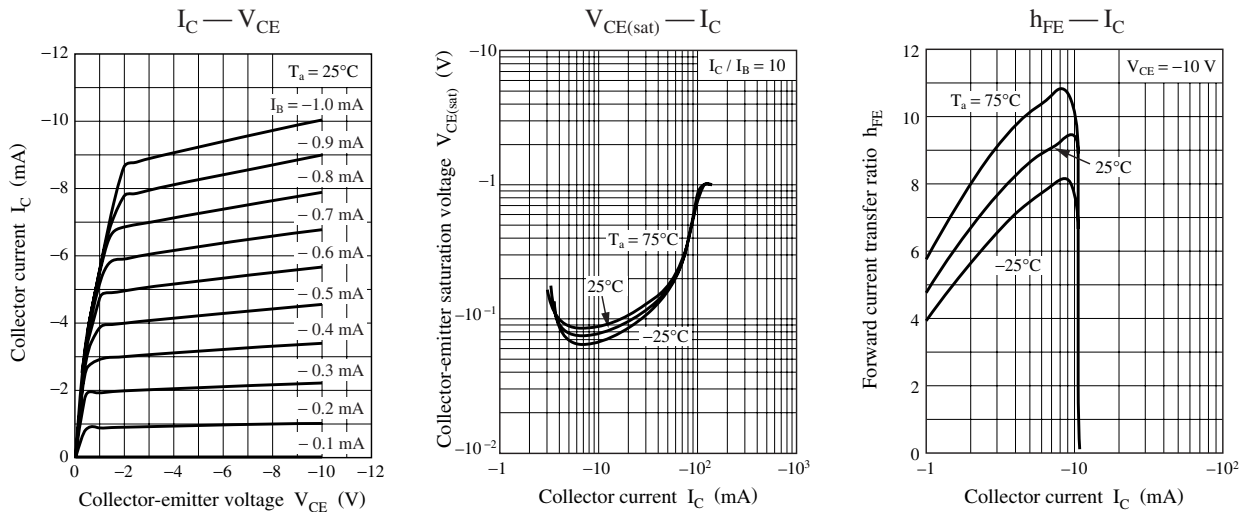
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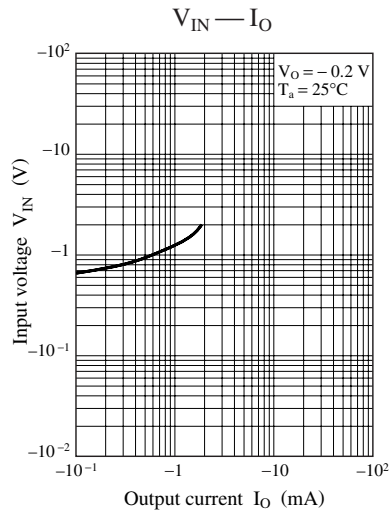
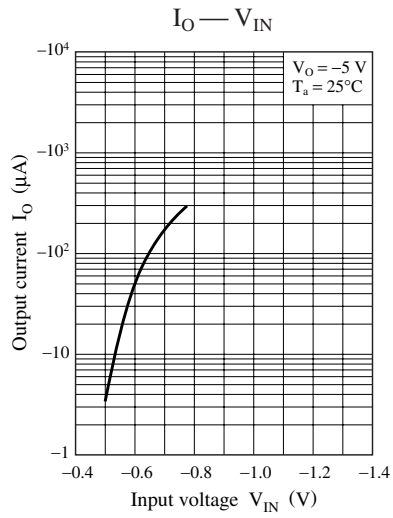


Characteristics charts of UNR911TG



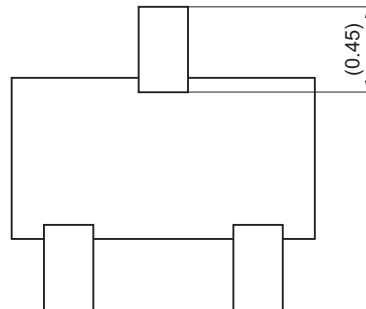
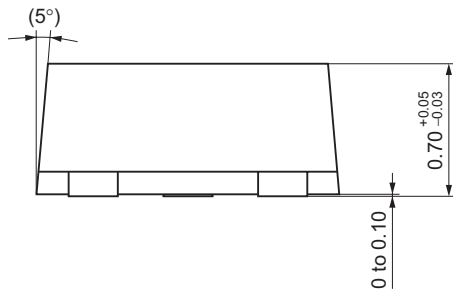
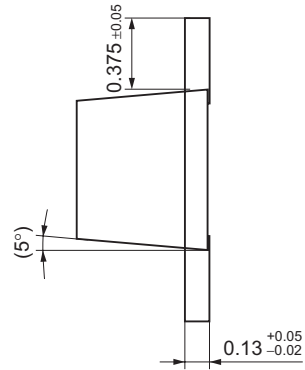
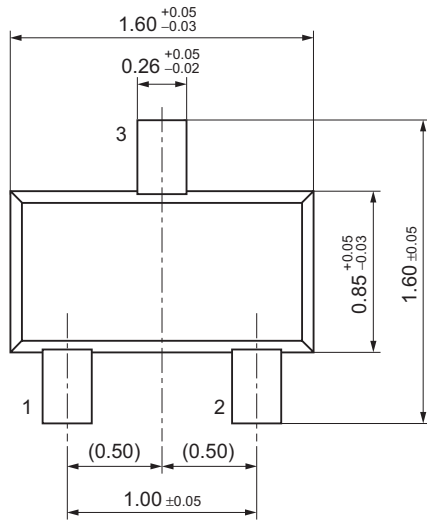
Characteristics charts of UNR911VG





SSMini3-F3

Unit: mm



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